Voltage Regulators, Peak Power Zener Surge Rated, 600 Watt

BZG03C15 Series

The SMA series is supplied in ON Semiconductor's exclusive, cost-effective, highly reliable SURMETIC $^{\text{\tiny{M}}}$ package and is ideally suited for use in communication systems, automotive, numerical controls, process controls, medical equipment, business machines, power supplies and many other industrial/consumer applications. This new line of 1.5 watt Zener diodes offers the following advantages:

Specification Features

- Standard Zener Breakdown Voltage 15 V to 150 V
- Peak Power 600 Watts @ 100 μs
- ESD Rating of Class 3 (> 16 KV) per Human Body Model
- Response Time is Typically < 1.0 ns
- Flat Handling Surface for Accurate Placement
- Package Design for Top Slide or Bottom Circuit Board Mounting
- Low Profile Package
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Mechanical Characteristics

CASE: Void-free, transfer-molded plastic

FINISH: All external surfaces are corrosion resistant and leads are readily solderable

MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

POLARITY: Cathode indicated by molded polarity notch or polarity

MOUNTING POSITION: Any



ON Semiconductor®

www.onsemi.com

PLASTIC SURFACE MOUNT ZENER VOLTAGE REGULATORS 600 WATTS PEAK POWER





SMA CASE 403D

MARKING DIAGRAM



XXX = Specific Device Code (See Table on Page 2)

A = Assembly Location

Y = Year
WW = Work Week
Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping [†]
BZG03C15G	SMA (Pb-Free)	5000/Tape & Reel
BZG03C150G	SMA (Pb-Free)	5000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

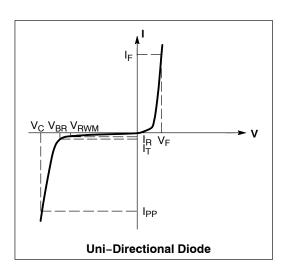
BZG03C15 Series

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Power Dissipation (Note 1) @ T_L = 25°C, t_P = 100 μs	P _{ZSM}	600	W
DC Power Dissipation @ T _L = 75°C Measured Zero Lead Length (Note 2) Derate Above 75°C Thermal Positones I water to Lead	P _D	1.5	W mW/°C °C/W
Thermal Resistance, Junction-to-Lead Forward Surge Current (Note 3) @ T _A = 25°C	R _{0JL}	50 40	A A
Operating and Storage Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. $100 \, \mu s$, non-repetitive square pulse
- 2. 1 in. square copper pad, FR-4 board
- 3. 1/2 sine wave (or equivalent square wave), PW = 8.3 ms, duty cycle = 4 pulses per minute maximum



SYMBOLS DEFINITIONS

Symbol	Parameter					
I _{PP}	Maximum Reverse Peak Pulse Current					
V _C Clamping Voltage @ I _{PP}						
V _{RWM}	Working Peak Reverse Voltage					
I _R	Maximum Reverse Leakage Current @ V _{RWM}					
V_{BR}	Breakdown Voltage @ I _T					
I _T	Test Current					
IF	Forward Current					
V _F	Forward Voltage @ I _F					

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted, $V_F = 1.2 \text{ V Max.}$ @ $I_F = 0.5 \text{ A}$ for all types)

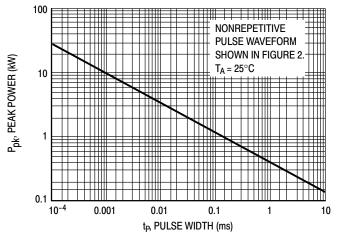
				Breakdown Voltage			9	Z _{zt} @ I _T	
	Device	V _{RWM} (Note 4)	I _R @ V _{RWM}	V_{BR} (V) (Note 5)		@ I _T	Тур	Max	
Device*	Marking	Volts	μΑ	Min	Nom	Max	mA	Ω	Ω
BZG03C15, G	G15	11	1	13.8	15.0	15.6	50	5.0	10.0
BZG03C150, G	G150	110	1	138	150	156	5	130	300

^{4.} A transient suppressor is normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal to or greater than the DC or continuous peak operating voltage level

^{5.} V_{BR} measured at pulse test current I_T at an ambient temperature of 25°C *The "G" suffix indicates Pb–Free package available.

BZG03C15 Series

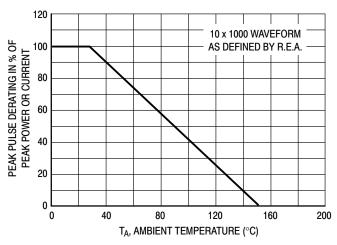
RATING AND TYPICAL CHARACTERISTIC CURVES



10,000 $T_J = 25^{\circ}C$ f = 1 MHz **MEASURED AT** V_{sig} = 50 m V_{p-p} C, CAPACITANCE (pF) 000 001 **ZERO BIAS** MEASURED AT STAND-OFF $VOLTAGE,\,V_{WM}$ 10 2 10 20 50 100 200 5 V(BR), BREAKDOWN VOLTAGE (VOLTS)

Figure 1. Pulse Rating Curve

Figure 3. Typical Junction Capacitance



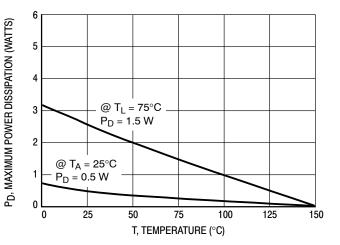


Figure 2. Pulse Derating Curve

Figure 4. Steady State Power Derating

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MECHANICAL CASE OUTLINE

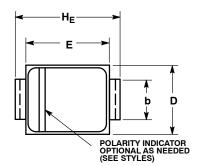
PACKAGE DIMENSIONS





SMA CASE 403D ISSUE H

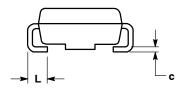
DATE 23 SEP 2015

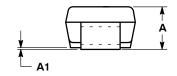




- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION b SHALL BE MEASURED WITHIN DIMENSION L.

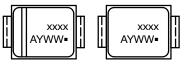
	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	1.97	2.10	2.20	0.078	0.083	0.087	
A1	0.05	0.10	0.20	0.002	0.004	0.008	
b	1.27	1.45	1.63	0.050	0.057	0.064	
С	0.15	0.28	0.41	0.006	0.011	0.016	
D	2.29	2.60	2.92	0.090	0.103	0.115	
E	4.06	4.32	4.57	0.160	0.170	0.180	
HE	4.83	5.21	5.59	0.190	0.205	0.220	
L	0.76	1.14	1.52	0.030	0.045	0.060	





MARKING DIAGRAM*

GENERIC



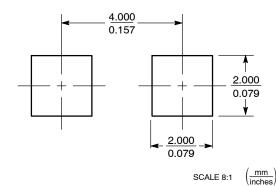
STYLE 1 STYLE 2

= Specific Device Code XXXX = Assembly Location Α Υ = Year

ww = Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLE 2: NO POLARITY STYLE 1: PIN 1. CATHODE (POLARITY BAND)

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DESCRIPTION:	SMA		PAGE 1 OF 1		

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